

## FEATURES

Ideally suited for automatic insertion  
 For Switching and AF Amplifier Applications

**BC856A/B** (PNP)  
**BC857A/B/C** (PNP)  
**BC858A/B/C** (PNP)

### Marking

BC856A	BC856B	BC857A	BC857B
3A	3B	3E	3F
BC857C	BC858A	BC858B	BC858C
3G	3J	3K	3L

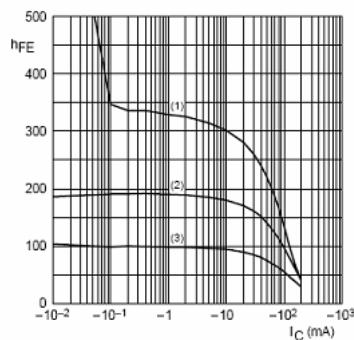


### MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Parameter		Symbol	Value	Unit
Collector-Base Voltage	BC856	V <sub>CBO</sub>	-80	V
	BC857	V <sub>CBO</sub>	-50	
	BC858	V <sub>CBO</sub>	-30	
Collector-Emitter Voltage	BC856	V <sub>CEO</sub>	-65	V
	BC857	V <sub>CEO</sub>	-45	
	BC858	V <sub>CEO</sub>	-30	
Emitter-Base Voltage		V <sub>EBO</sub>	-5	V
Collector Current -Continuous		I <sub>C</sub>	-0.1	A
Collector Power Dissipation		P <sub>C</sub>	0.2	W
Junction Temperature		T <sub>j</sub>	150	°C
Storage Temperature		T <sub>stg</sub>	-55 to +150	°C

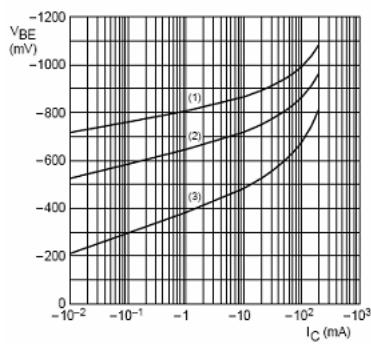
ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)

Parameter		Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	BC856	VCBO	I <sub>C</sub> = -10μA, I <sub>E</sub> =0	-80		
	BC857			-50		V
	BC858			-30		
Collector-emitter breakdown voltage	BC856	VCEO	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-65		
	BC857			-45		V
	BC858			-30		
Emitter-base breakdown voltage		VEBO	I <sub>E</sub> = -1μA, I <sub>C</sub> =0	-5		V
Collector cut-off current	BC856	I <sub>CBO</sub>	V <sub>CB</sub> = -70 V , I <sub>E</sub> =0			
	BC857		V <sub>CB</sub> = -45 V , I <sub>E</sub> =0		-0.1	μA
	BC858		V <sub>CB</sub> = -25 V , I <sub>E</sub> =0			
Collector cut-off current	BC856	I <sub>CEO</sub>	V <sub>CE</sub> = -60 V , I <sub>B</sub> =0			
	BC857		V <sub>CE</sub> = -40 V , I <sub>B</sub> =0		-0.1	μA
	BC858		V <sub>CE</sub> = -25 V , I <sub>B</sub> =0			
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = -5 V , I <sub>C</sub> =0		-0.1	μA
DC current gain	BC856A, 857A, 858A	h <sub>FE</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA	125	250	
	BC856B, 857B, 858B			220	475	
	BC857C, BC858C			420	800	
Collector-emitter saturation voltage		V <sub>CE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> = -5 mA		-0.5	V
Base-emitter saturation voltage		V <sub>BE(sat)</sub>	I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA		-1.1	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -10mA f=100MHz	100		MHz
Collector capacitance		C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		4.5	pF

**BC856A/B**  
**BC857A/B/C** Typical Characteristics  
**BC858A/B/C**


BC857A; V<sub>CE</sub> = -5 V.  
(1) T<sub>amb</sub> = 150 °C.  
(2) T<sub>amb</sub> = 25 °C.  
(3) T<sub>amb</sub> = -55 °C.

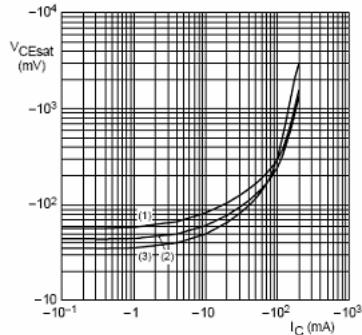
Fig.2 DC current gain as a function of collector current; typical values.



BC857A; V<sub>CE</sub> = -5 V.  
(1) T<sub>amb</sub> = -55 °C.  
(2) T<sub>amb</sub> = 25 °C.  
(3) T<sub>amb</sub> = 150 °C.

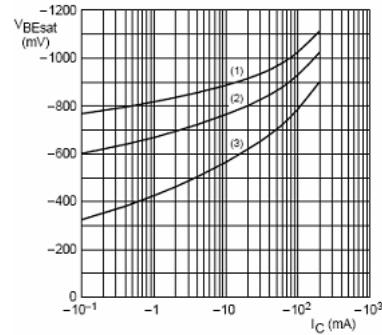
Fig.3 Base-emitter voltage as a function of collector current; typical values.

## BC856A/B BC857A/B/C Typical Characteristics BC858A/B/C



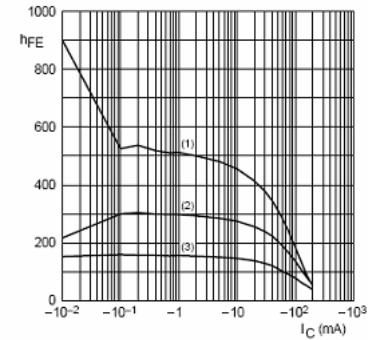
BC857A;  $I_C/I_B = 20$ .  
 (1)  $T_{amb} = 150^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = -55^\circ C$ .

Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values.



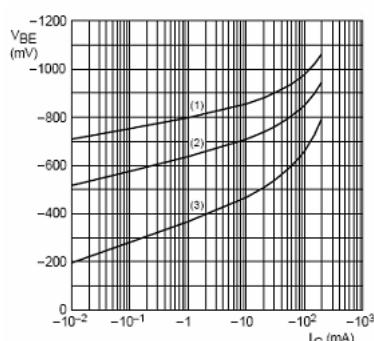
BC857A;  $I_C/I_B = 20$ .  
 (1)  $T_{amb} = -55^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = 150^\circ C$ .

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.



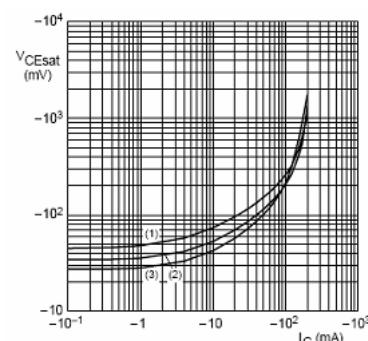
BC857B;  $V_{CE} = -5 V$ .  
 (1)  $T_{amb} = 150^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = -55^\circ C$ .

Fig.6 DC current gain as a function of collector current; typical values.



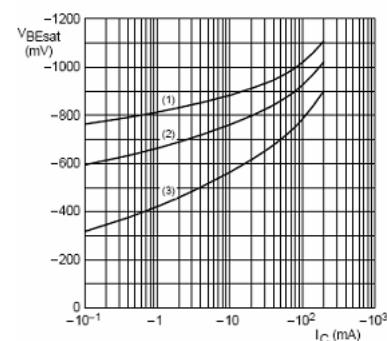
BC857B;  $V_{CE} = -5 V$ .  
 (1)  $T_{amb} = -55^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = 150^\circ C$ .

Fig.7 Base-emitter voltage as a function of collector current; typical values.



BC857B;  $I_C/I_B = 20$ .  
 (1)  $T_{amb} = 150^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = -55^\circ C$ .

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.



BC857B;  $I_C/I_B = 20$ .  
 (1)  $T_{amb} = -55^\circ C$ .  
 (2)  $T_{amb} = 25^\circ C$ .  
 (3)  $T_{amb} = 150^\circ C$ .

Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.